

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**Applicant:** William G. America **Conf. No.:** 3775  
**Serial No.:** 10/709,776 **Art Unit:** 2811  
**Filed:** 05/27/2004 **Examiner:** Im, Junghwa M.  
**Docket No.:** FIS920040083US1  
(IBMF-0058)

**Title:** **SEMICONDUCTOR DEVICE FORMED BY IN-SITU MODIFICATION OF DIELECTRIC LAYER AND RELATED METHODS**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Sir:

**I. INTRODUCTORY COMMENTS**

This paper is being filed in response to the non-final Office Action dated December 1, 2008. Please amend the above-referenced patent application as follows:

**The Amendments to the Claims** begins on page 2 of this paper.

**Remarks** begin on page 4 of this paper.

**The Conclusion** appears at page 7 of this paper.